



MEMC 98-5751 (2358.4)  
PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of Mutti et al.

Serial No. 10/008,812

Filed November 13, 2001

For METHOD FOR CONTROLLING GROWTH OF A SILICON CRYSTAL TO MINIMIZE  
GROWTH RATE AND DIAMETER DEVIATIONS

February 5, 2002

TO THE COMMISSIONER OF PATENTS AND TRADEMARKS,

SIR:

**INFORMATION DISCLOSURE STATEMENT**

\* In accordance with 37 C.F.R. 1.97 and 1.98 and MPEP 609, and in compliance with the duty  
of disclosure set forth in 37 C.F.R. 1.56, applicants submit the attached PTO/SB/08A for  
consideration by the Patent and Trademark Office in the above-entitled application and to be made  
of record therein. The references listed on the attached PTO/SB/08A have been previously  
submitted in parent application Serial No. 09/495,563 and, therefore, in accordance with MPEP 609,  
are not being provided at this time.

Respectfully submitted,

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